

Charge Dynamics in (ω, Q) -Space Studied by Inelastic X-ray Scattering

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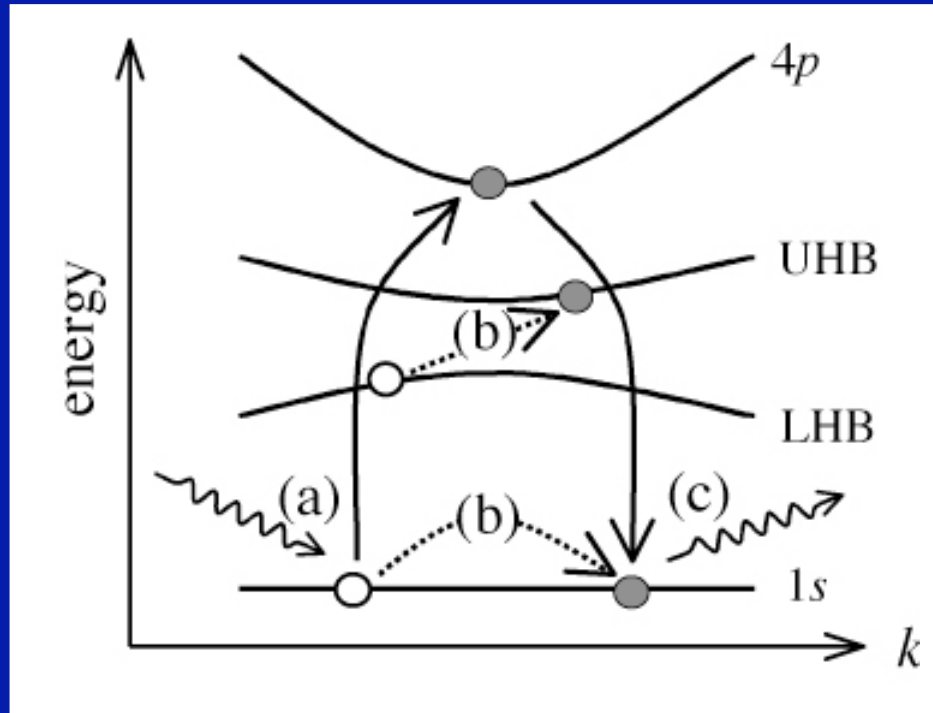


Inelastic X-ray scattering

$$\begin{aligned}
 & \frac{1}{Z} \sum_{\mathbf{r}} \langle \mathbf{r} | \mathbf{r}' \rangle \left[\frac{1}{\omega - \epsilon(\mathbf{r})} - \frac{1}{\omega - \epsilon(\mathbf{r}')} \right] \langle \mathbf{r}' | \mathbf{r} \rangle \\
 & \frac{1}{Z} \sum_{\mathbf{r}} \langle \mathbf{r} | \mathbf{r}' \rangle \left[\frac{1}{\omega - \epsilon(\mathbf{r})} - \frac{1}{\omega - \epsilon(\mathbf{r}')} \right] \langle \mathbf{r}' | \mathbf{r} \rangle
 \end{aligned}$$

- The first term: non-resonant inelastic scattering
 - All electrons (Ze) are contributed \Rightarrow phonon excitation
- The second term: resonant inelastic scattering (RIXS)
 - Electrons on the **specific atom** are contributed.
 - Resonance enhancement
 - **Element specific** \Rightarrow electronic excitation

RIXS of 3d transition elements



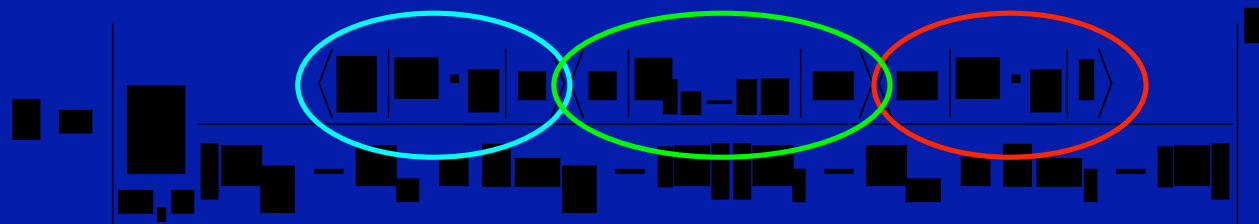
K-edge ($1s \rightarrow 4p$, several keV)

(a) absorption

(b) interaction between

$1s$ core-hole and $3d$ electron

(c) X-ray emission



Inelastic Scattering

$$I(Q, E) \sim \underbrace{[V(Q)]^2}_{\text{Interaction of probe}} [1 - e^{-\beta E}]^1 \cdot \underbrace{\text{Im } \chi(Q, E)}_{\text{Generalized susceptibility}}$$

Interaction of probe

Generalized susceptibility

- For neutrons → Spin susceptibility
- For X-rays → Nuclear susceptibility
- For electrons } → Charge susceptibility



$$\chi(Q, E) = -(Q^2/4\pi^2N) \underbrace{1/\epsilon(Q, E)}_{\text{Dynamical dielectric function}}$$

Dynamical dielectric function

Effects of electron-hole interaction on the dynamic structure factor: Application to nonresonant inelastic x-ray scattering

J. A. Soininen

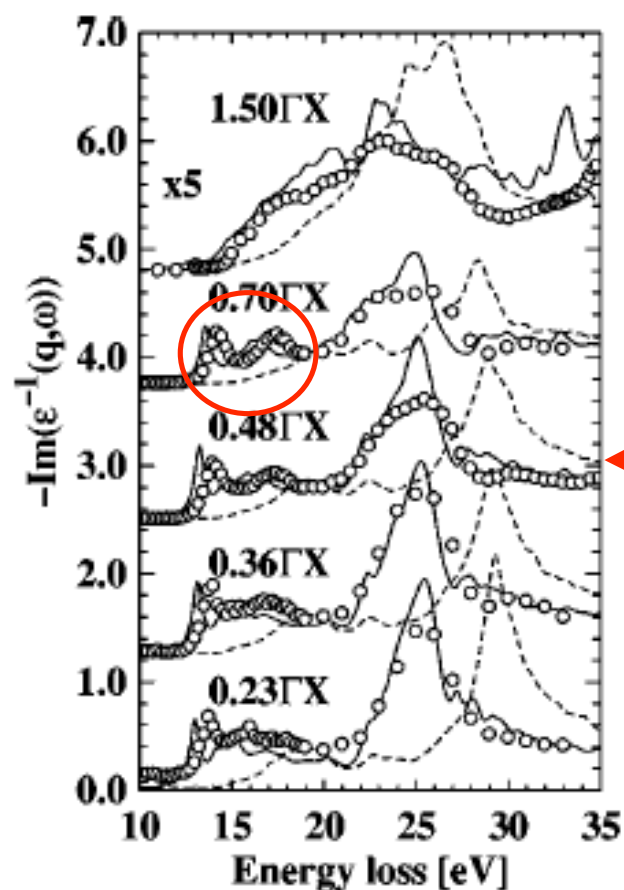
Department of Physics, POB 9, FIN-00014, University of Helsinki, .

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(Received 24 January 2000)

P. R. B. 61 ('00) 16423

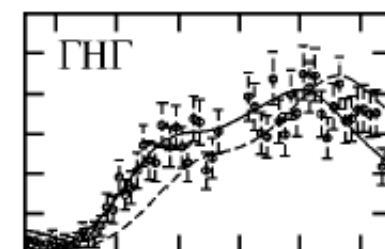
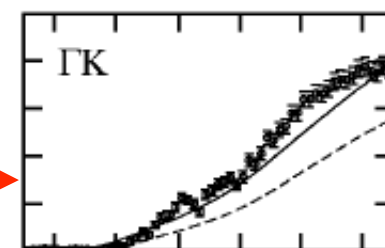
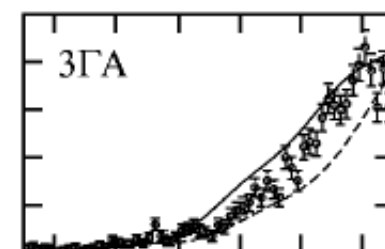
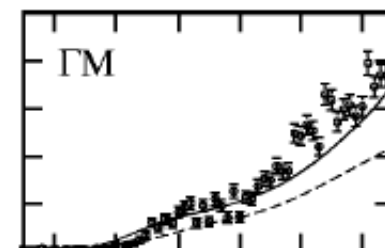


— : including
ele.-ho. inter.

..... : not including
ele.-ho. Inter.

LiF
insulator

GaN
semiconductor

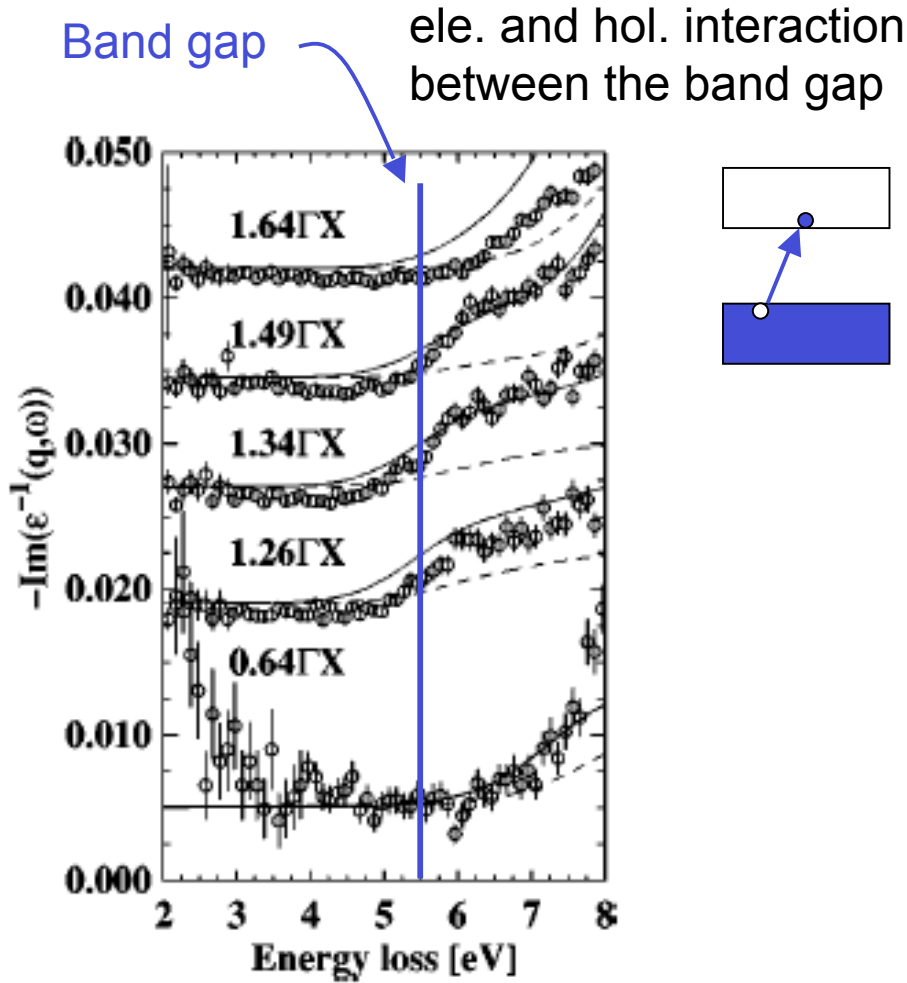


Intensity [arb. units]

Energy loss [eV]

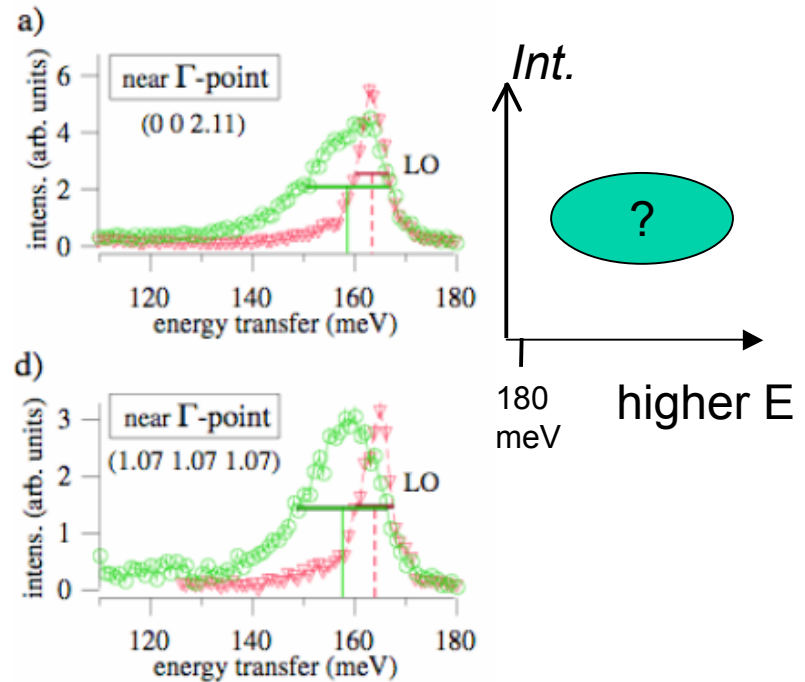
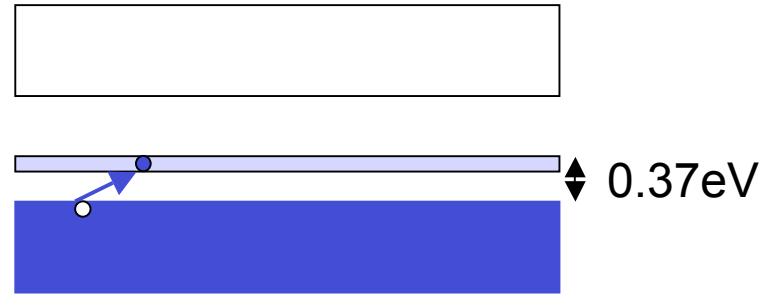
Non resonant IXS on Diamond

Properties of an indirect band gap

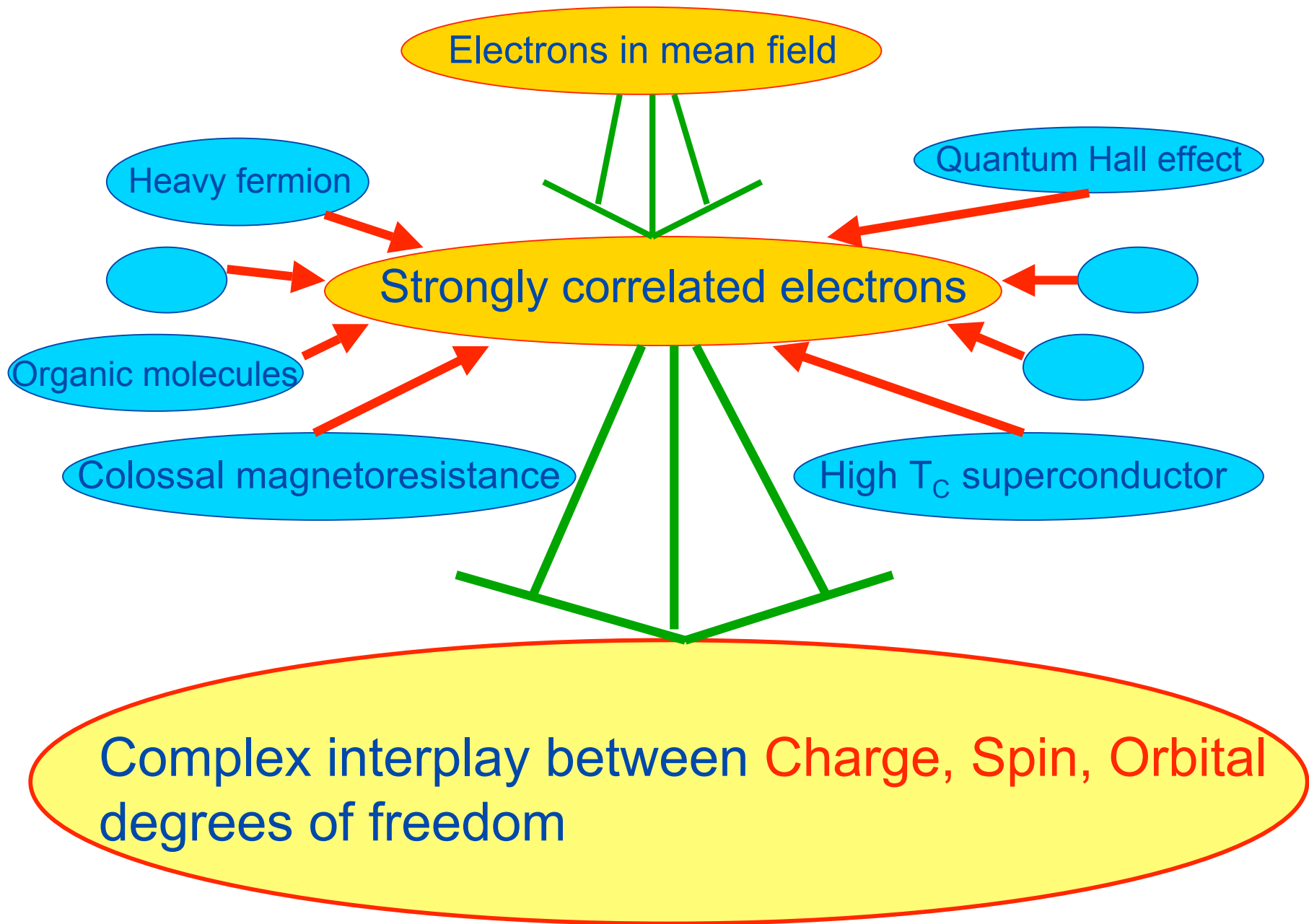


Caliebe et al., P.R.L. 84 ('00) 3907

- Band engineering of Semiconductors,
- Superconductor based on Semiconductors

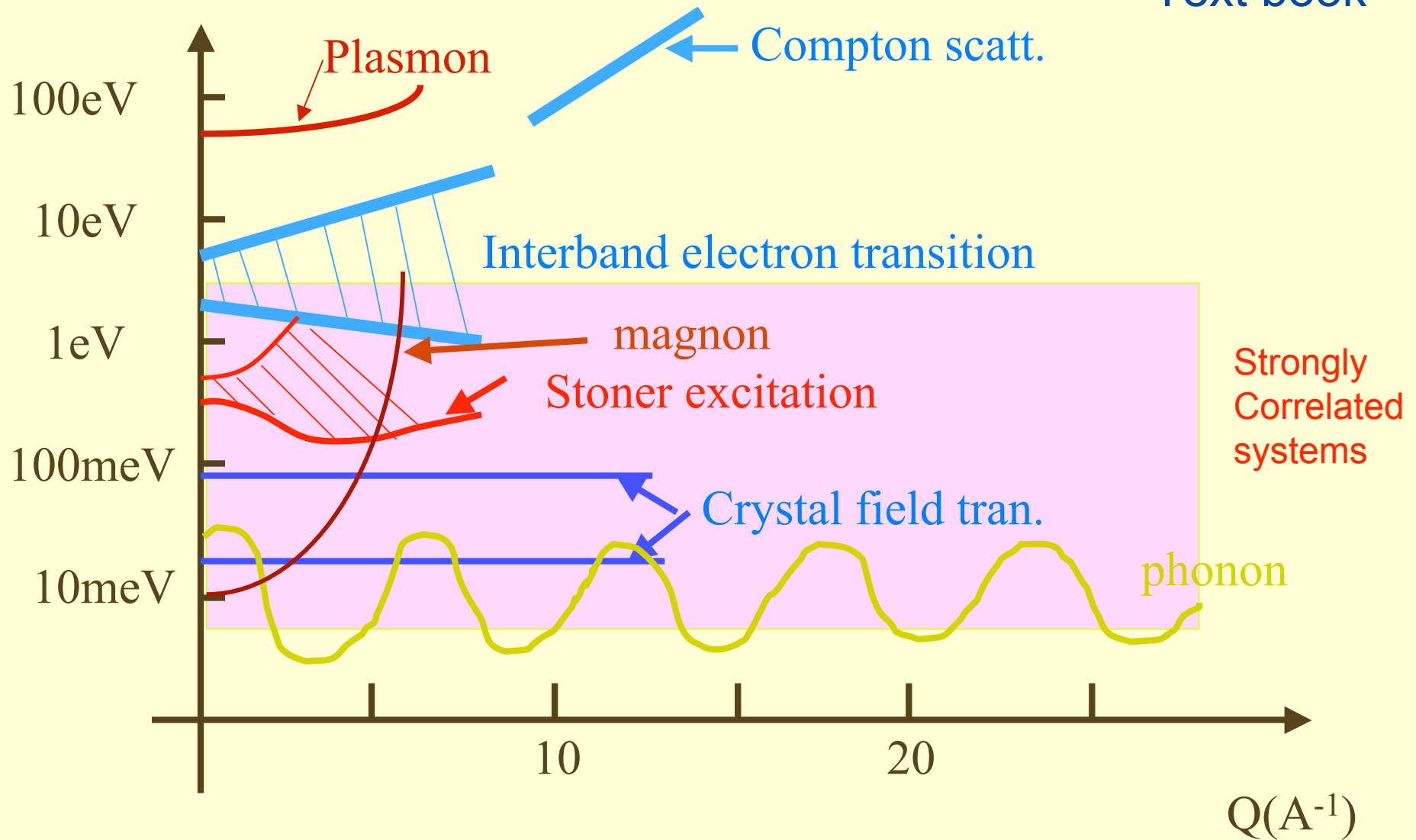


M. Hoesch, J. M. et al., P. R. B. 75 ('07) 140508(R)

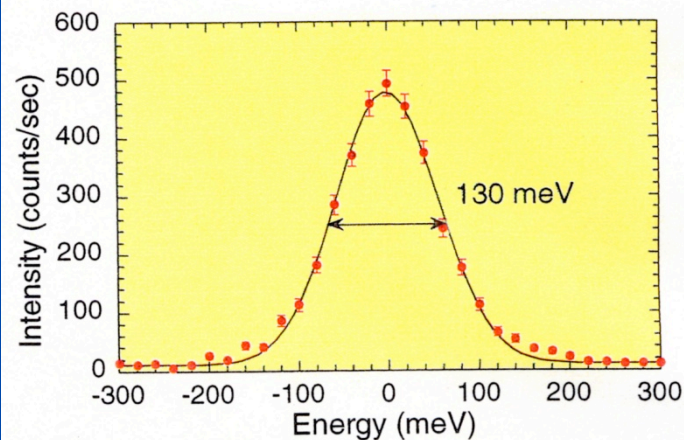
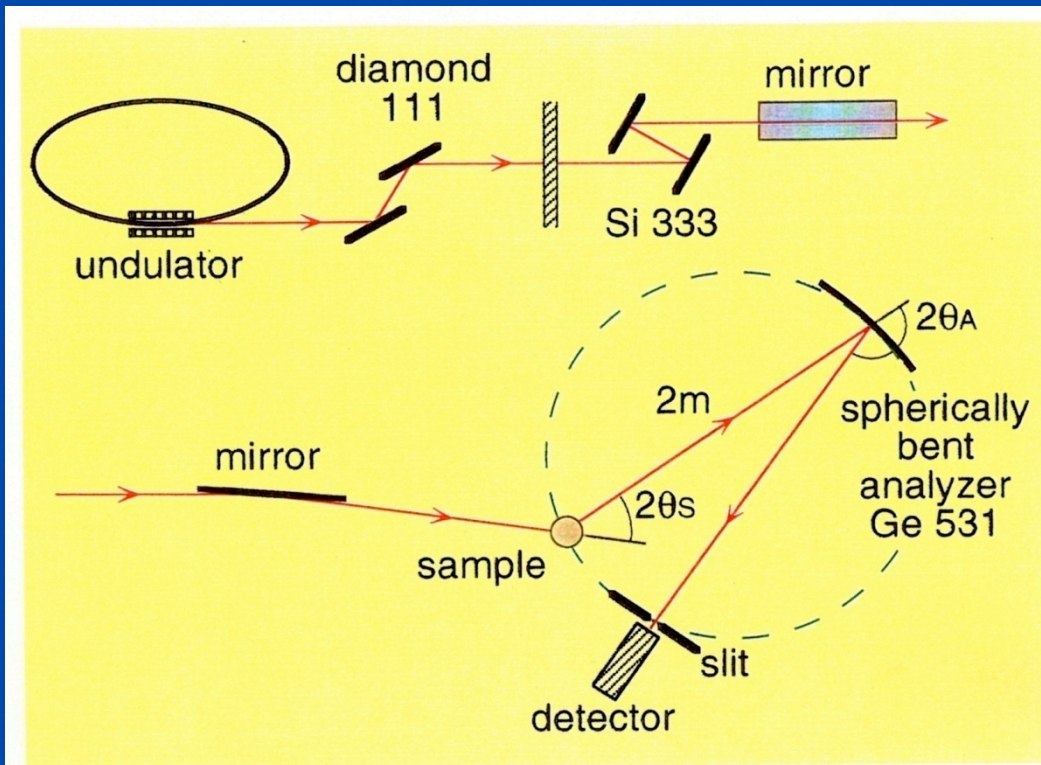


Elementary Excitations in Solids

Text book

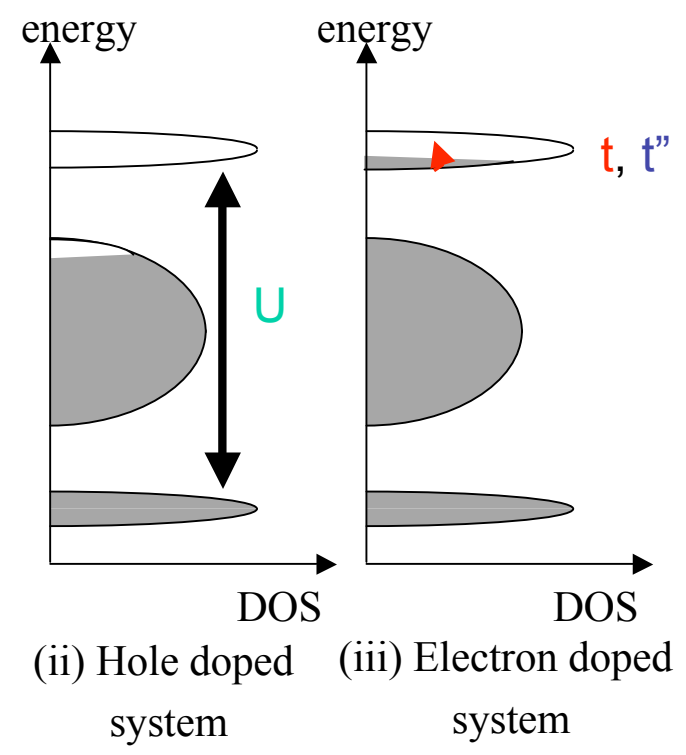
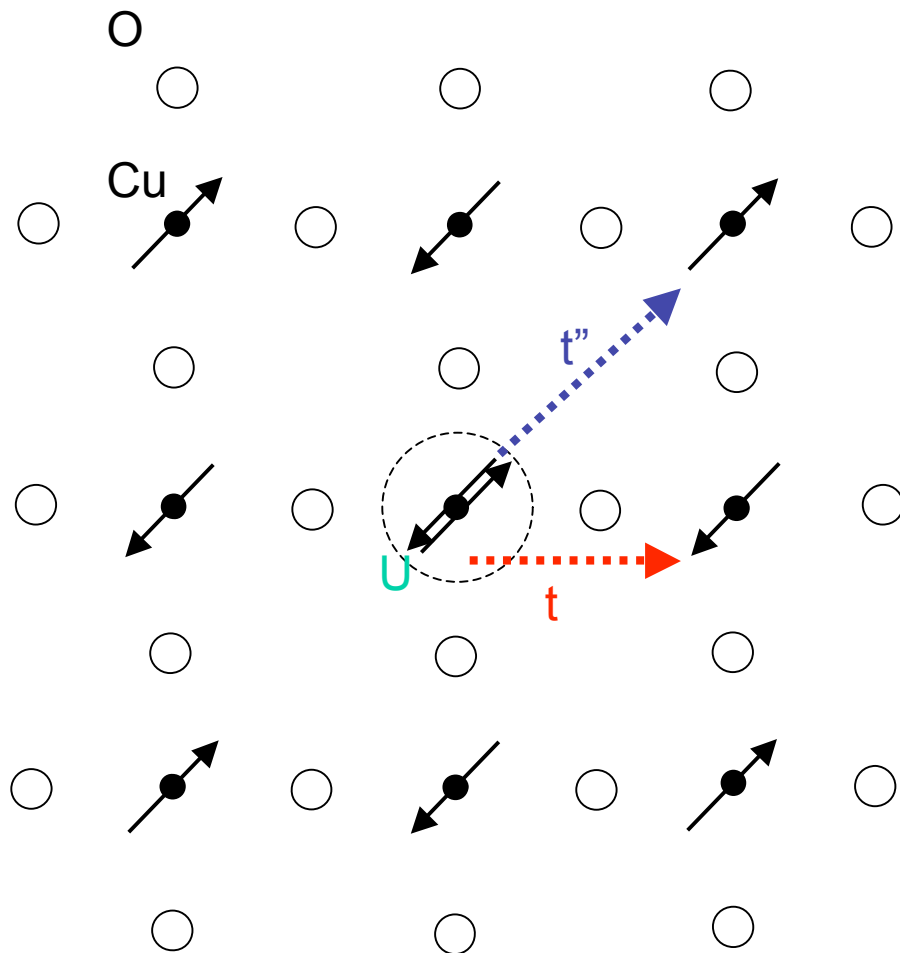


Set-up of Inelastic Scattering Spectrometer at BL-11XU



**Observed energy
Resolution
at 6.5 keV**

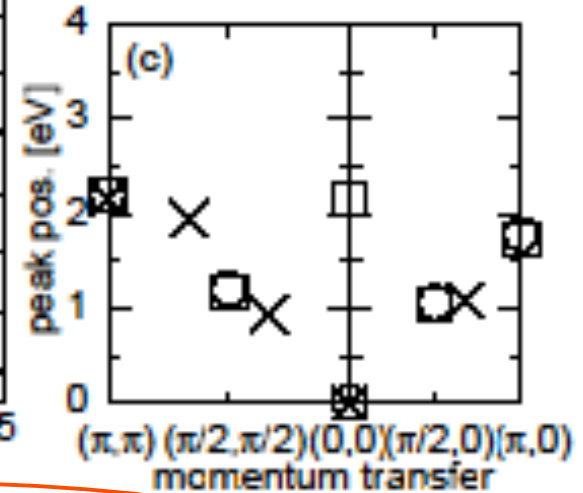
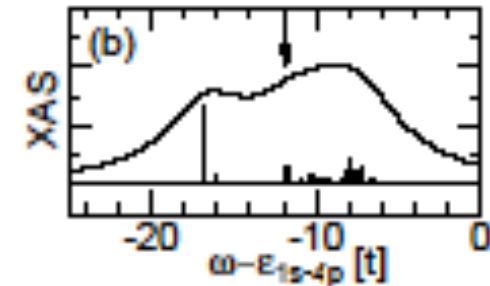
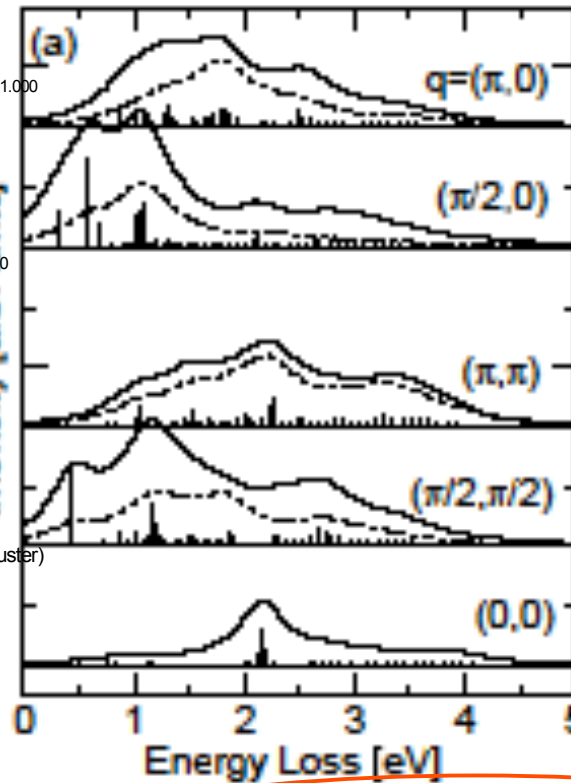
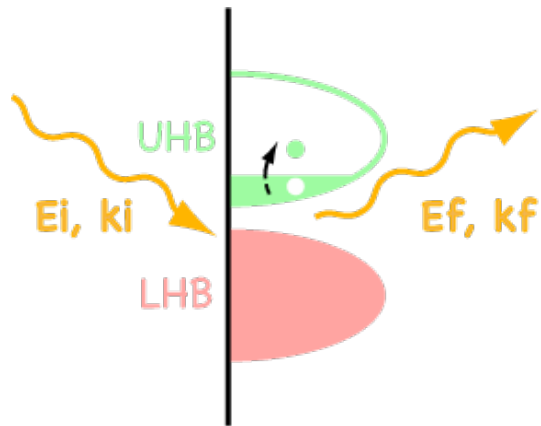
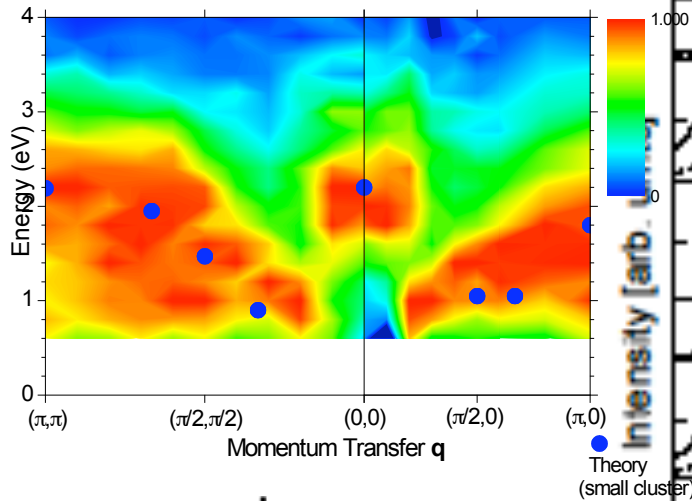
Schematic diagram of electronic states



Electron doping

X=0.15

Calculated by K. Tsutsui



- RIXS spectra
- Dynamical density response function

The electron involved in dynamical density response function can be selected by RIXS !

toward future

Required energy resolution

- Inter-band excitation: “U”~2eV

Excitations across the Mott / charge-transfer gap

$$\Delta E \sim 0.5 \text{ eV}$$

- Intra-band excitation: “t”~0.4eV

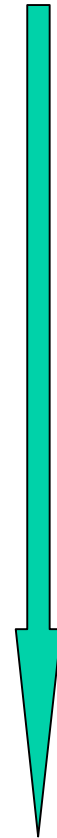
Excitations within bands across the Fermi level

$$\Delta E \sim 0.1 \text{ eV}$$

- Low-energy excitation: “J”~0.1eV

Excitations related to the spin degree of freedom

$$\Delta E \sim 0.05 \text{ eV}$$



Dynamical structure factor of IXS in the phonon energy region

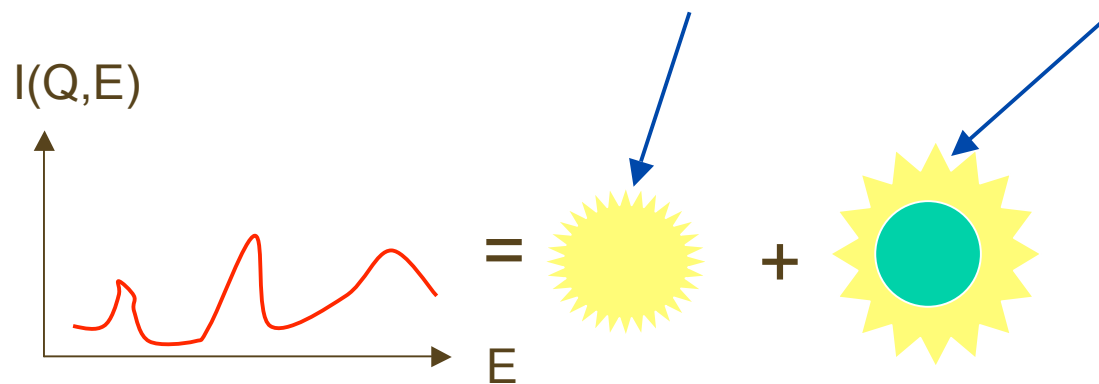
$$\varepsilon(Q, \omega) = \varepsilon_{\text{el}}(Q, \omega) + \varepsilon_{\text{ion}}(Q, \omega) - 1$$



$$\chi(Q, \omega) = -(Q^2/4\pi^2N) 1/\varepsilon(Q, \omega)$$



$$I(Q, \omega) = F(\varepsilon_{\text{el}}) + G(\varepsilon_{\text{el}}) \cdot H(\varepsilon_{\text{ion}})$$



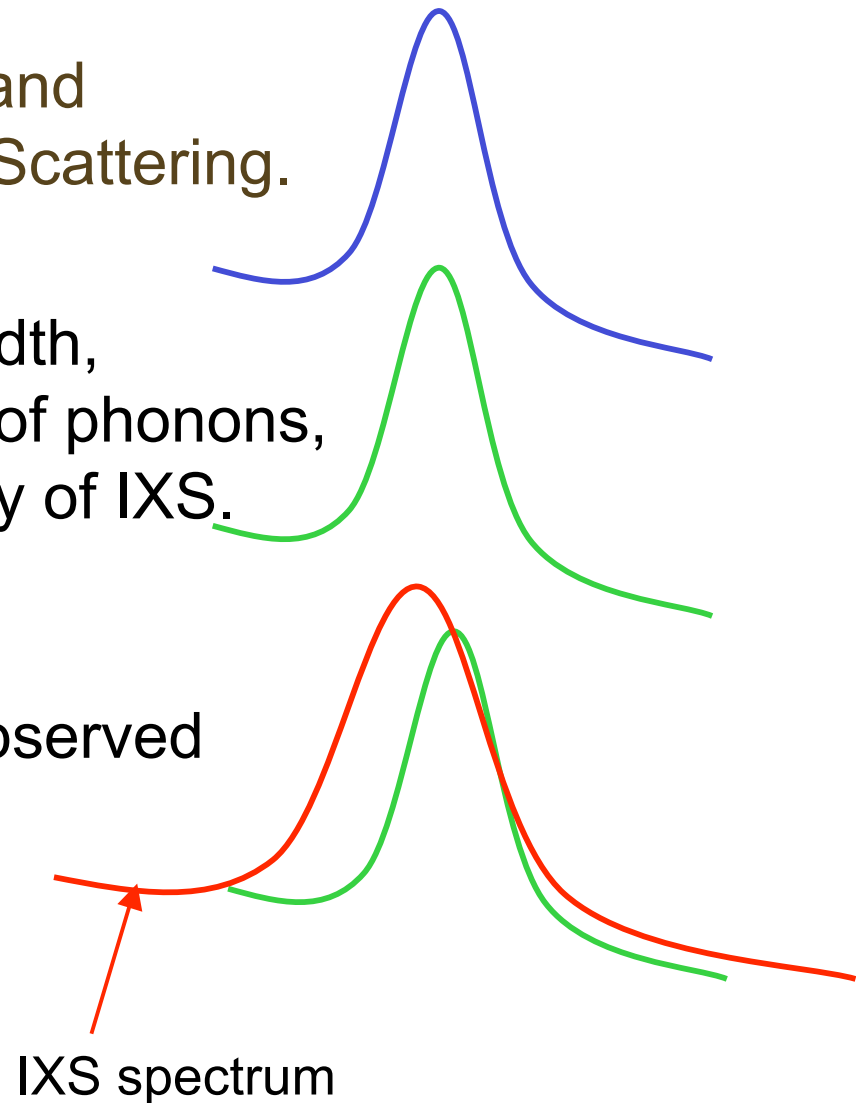
How to get the information on electric dynamical function

Collaboration between X-rays and Neutrons

1. Measure the phonon spectrum and dispersion by Neutron Inelastic Scattering.

2. Derive the information on the width, eigenvector and structure factor of phonons, and calculate the phonon intensity of IXS.
(C-IXS)

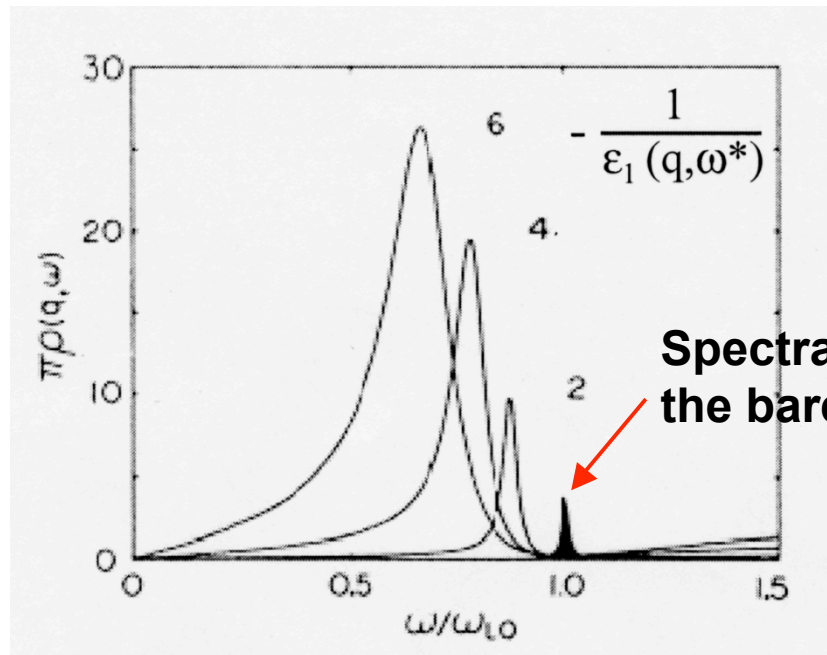
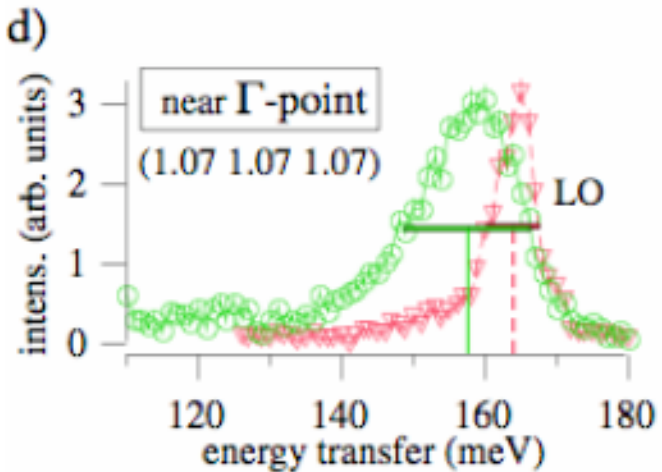
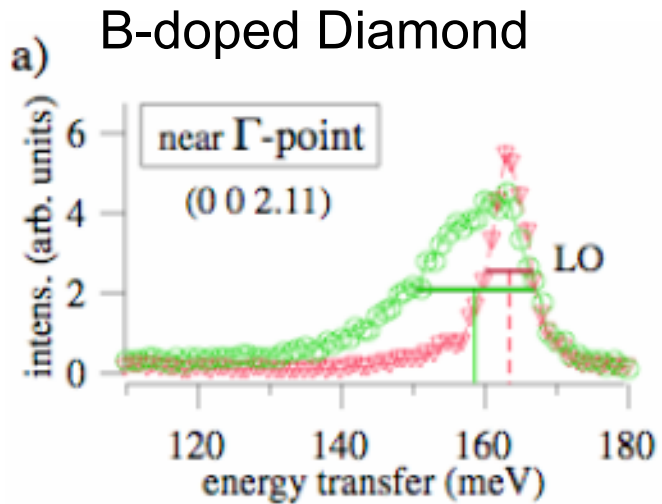
3. Compare the C-IXS with the observed IXS spectrum.



$$\epsilon(\mathbf{q}, \omega) = \epsilon_{el}(\mathbf{q}, \omega) + \epsilon_{ion}(\mathbf{q}, \omega) - 1.$$

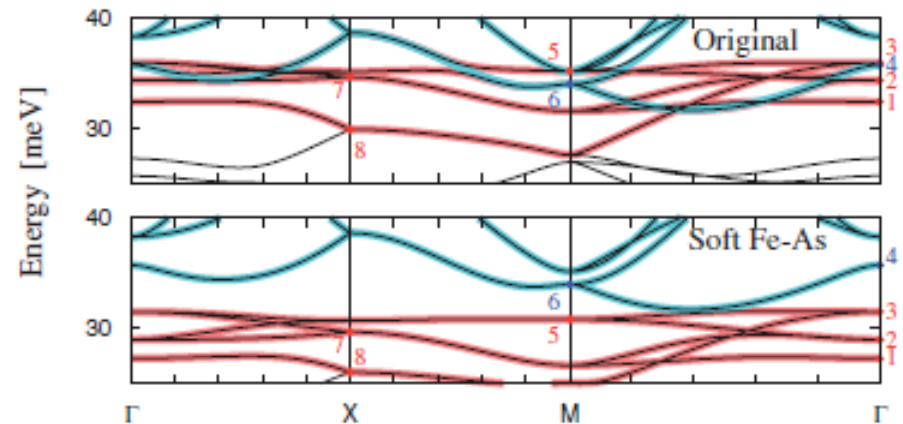
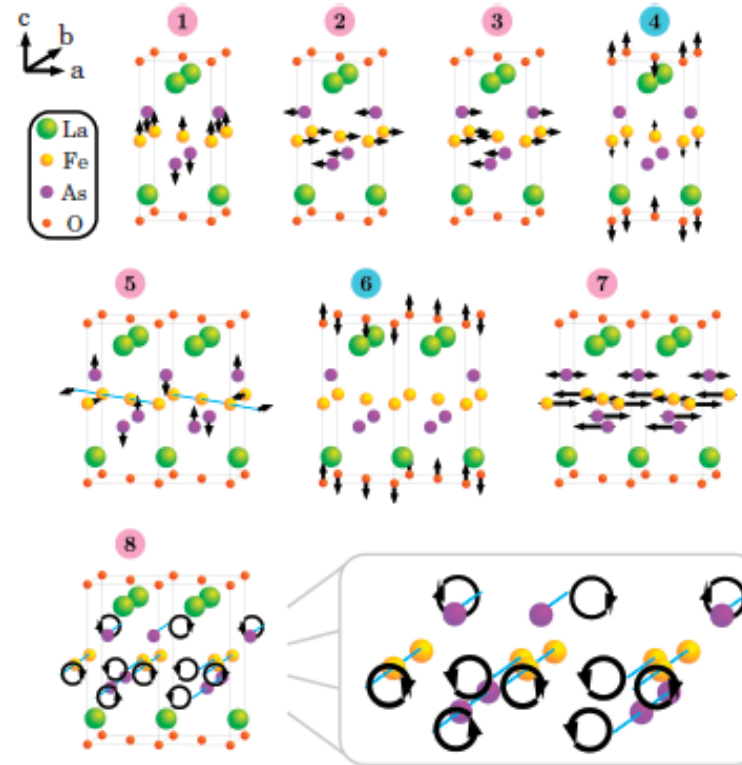
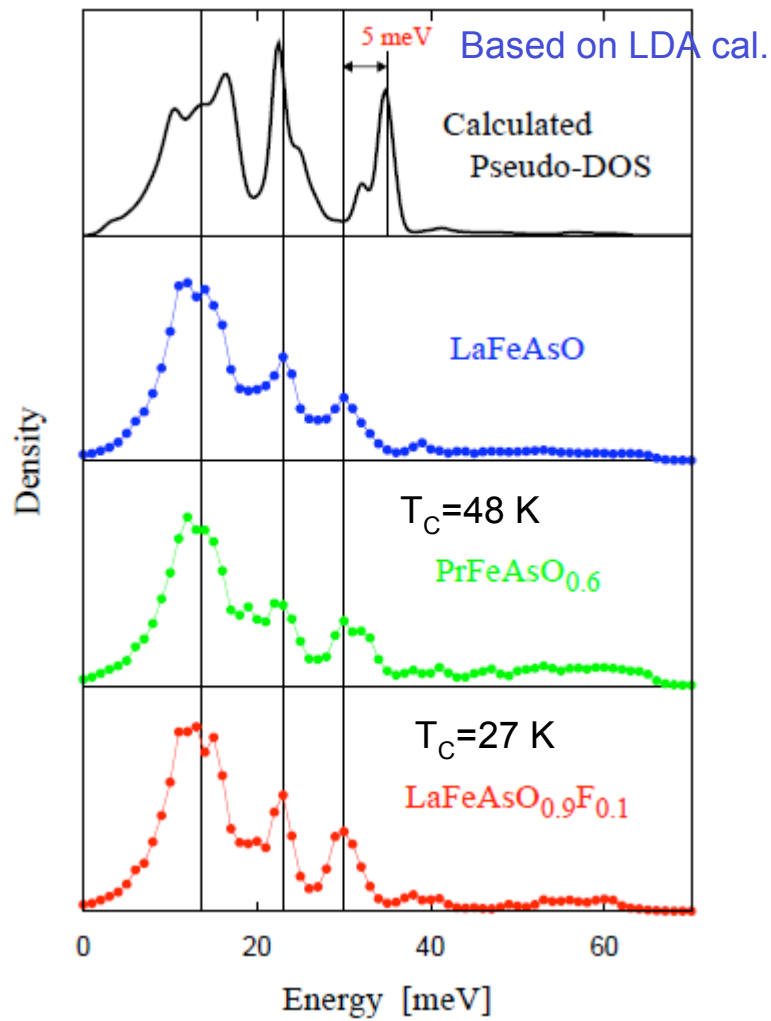
$$I(\mathbf{q}, \omega) = -\frac{1}{\pi} \text{Im} \left[\frac{1}{\epsilon(\mathbf{q}, \omega)} \right] \quad \text{(electric + phonon) part}$$

$$= -\frac{1}{\pi} \text{Im} \left[\frac{1}{\epsilon_{el}(\mathbf{q}, \omega)} \right] + \frac{\omega_{LO}^2(\mathbf{q}) - \omega_{TO}^2}{\epsilon_{el}(\mathbf{q}, \omega_{LO}^*)^2} \delta(\omega^2 - \omega_{LO}^{*2}),$$



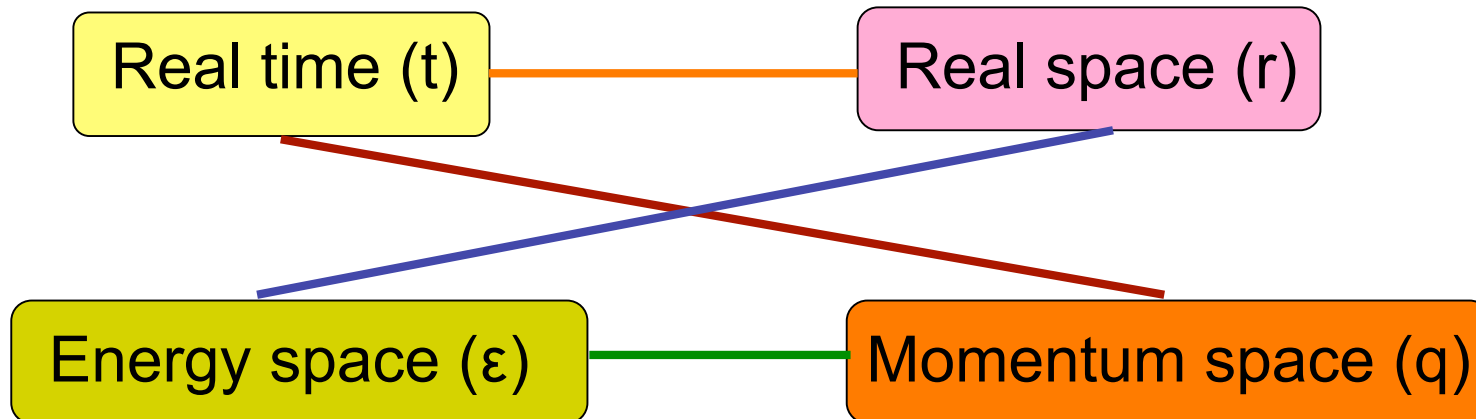
M. Tachiki et al., Phys. Rev. B38, ('88) 218.

Phonon DOS of Fe-based super.



Observation space

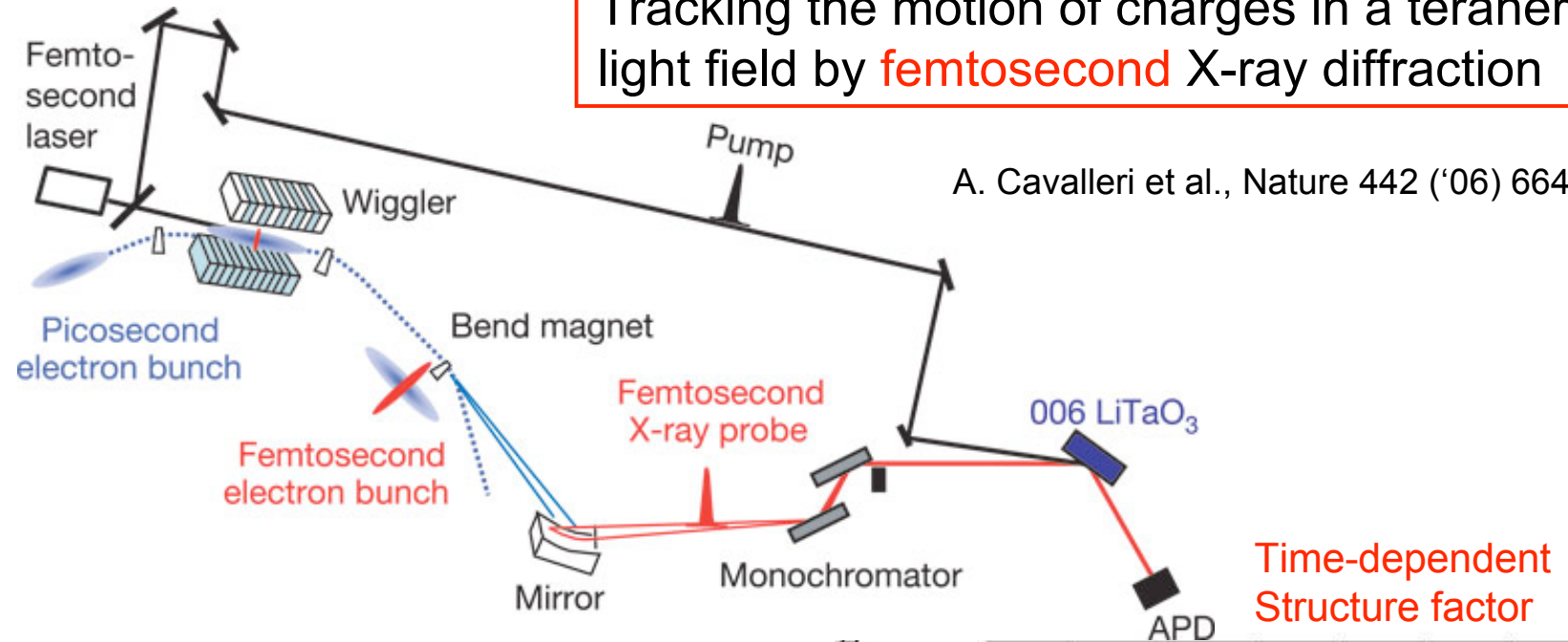
In what space should we measure physical properties?



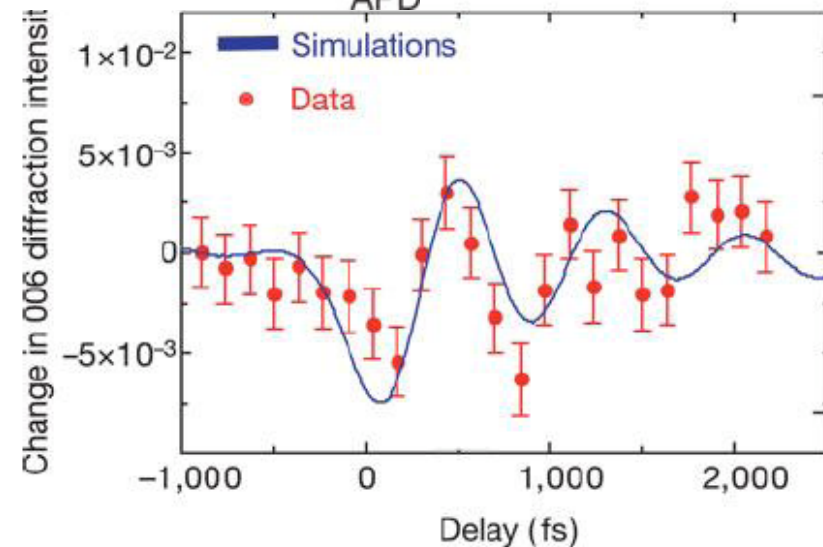
Dynamics in time domain

Tracking the motion of charges in a terahertz light field by femtosecond X-ray diffraction

A. Cavalleri et al., Nature 442 ('06) 664



Excitation of phonon polaritons in LiTaO₃



Collaborators for RIXS:

Experiment

K. Ikeuchi, I. Jarrige, M. Yoshida, T. Inami, J. Mizuki (SPring-8/JAEA)

H. Hiraka, K. Yamada, K. Kudo, Y. Koike, Y. Murakami (Tohoku Univ)

Y. Endoh (IAS)

Theory

K. Tsutsui (SPring-8/JAEA)

T. Tohyama (Kyoto Univ.)

S. Maekawa (Tohoku Univ.)

Beamline

H. Ishii, Y. Q. Cai (Taiwan-BL, SPring-8)

Collaborators for Fe- based Superconductors:

JAEA

- T. Fukuda, S. Shamoto, M. Ishikado, J. Mizuki, M. Arai,

SPring-8/RIKEN, JASRI

- A. Q. R. Baron, S. Tsutsui, H. Uchiyama

JST

- H. Nakamura, M. Machida

AIST

- A. Iyo, H. Kito, H. Eisaki

TIT

- H. Hosono

Importance of the collaboration between Experiment and theory

